



Revision 0.91

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**





### General Product Information

Product	Application
Tunable 780 nm DFB Laser	Spectroscopy
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	THz Generation
with integrated Beam Collimation	

EYP-DFB-0780-00080-1500-BFW01-0002



## Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-40		85
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		50
Forward Current	I <sub>F</sub>	mA			190
Reverse Voltage	$V_R$	V			2
Output Power	$P_{\text{opt}}$	mW			90
TEC Current	I <sub>TEC</sub>	Α			1.1
TEC Voltage	$V_{TEC}$	V			2.8

#### **Measurement Conditions / Comments**

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

#### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_LD$	°C	15		45
Forward Current	I <sub>F</sub>	mA			180
Output Power	$P_{\text{opt}}$	mW	20		80

## Characteristics at T<sub>LD</sub> = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	779	780	781
Linewidth (FWHM)	Δλ	MHz		2	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm		1500	
Sidemode Supression Ratio	SMSR	dB	30	50	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dI	nm / mA		0.003	

see images on page 4	
$P_{opt} = 80 \text{ mW}$	
reached by temperature modulation	
$P_{opt} = 80 \text{ mW}$	

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Characteristics at T <sub>LD</sub> = 25°	C at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Mode-hop free Temperature Range	T <sub>LD</sub>	° C	15		40
Mode-hop free Power Range	P <sub>opt</sub>	mW	20		80
Laser Current @ P <sub>opt</sub> = 80 mW	$I_{LD}$	mA			180
Slope Efficiency	η	W/A	0.6	0.8	1.1
Threshold Current	I <sub>th</sub>	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	0		0.1	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		0.1	
Beam Diameter horizontal (1/e²)	d	mm		1.0	1.2
Beam Diameter vertical (1/e²)	d.	mm		0.8	1.2

Measurement Conditions / Comments  Temperature at Laser Chip  parallel to the base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>opt</sub>	μA/mW	1		20

Meas	urement Conditions / Comments
$J_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		0.4	
Voltage	$U_TEC$	V		1.3	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 80 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 80 \text{ mW}, \Delta T =  Tcase - TLD $

Thermistor (Standard NTC Type)							
Parameter	Symbol	Unit	min	typ	max		
Resistance	R	kΩ		10			
Beta Coefficient	β			3892			
Steinhart & Hart Coefficient A	А		1.1293 x 10 <sup>-3</sup>				
Steinhart & Hart Coefficient B	В		2.3410 x 10 <sup>-4</sup>				
Steinhart & Hart Coefficient C	С			8.7755 x 10	-8		

Measurement Conditions / Comments						
$T_{LD} = 25^{\circ} C$						
$R_1  /  R_2 = e^{\beta  (1/T_1  -  1/T_2)} $ at $T_{LD} =$	0° 50° C					
$1/T = A + B(\ln R) + C(\ln R)^3$						
T: temperature in Kelvin						
R: resistance at T in Ohm						

## EYP-DFB-0780-00080-1500-BFW01-0002



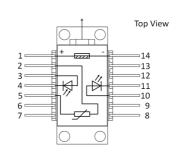
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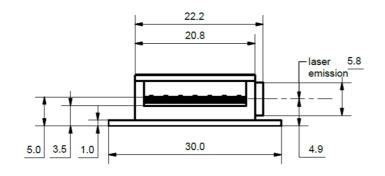


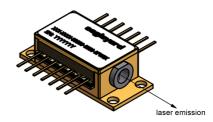
## Pin Assignment

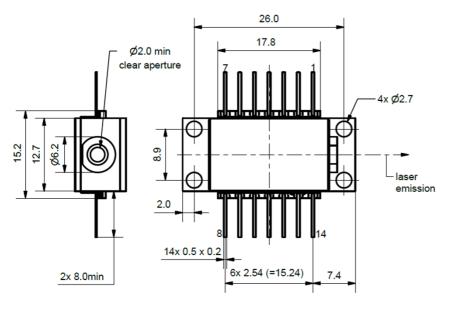
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)		
2	Thermistor	13	Case		
3	Photodiode (Anode)	12	not connected		
4	Photodiode (Cathode)	11	Laser Diode (Cathode)		
5	Thermistor	10	Laser Diode (Anode)		
6	not connected	9	not connected		
7	not connected	8	not connected		
Pins are isolated from case unless noted otherwise.					



### Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com

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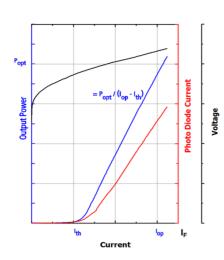
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## SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser

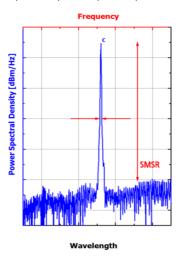


#### Typical Measurement Results

Output Power vs. Current



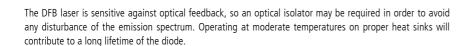
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 780 nm
MAX. OUTPUT POWER 90 mW



